

PHOTO DIODES 2.4 μm

Model PD24-20-TEC 2.4 mm 2.0 mm

One stage Thermoelectrically Cooled InGaAsSb photodiodes

Photodiodes **PD24-20-TEC** are designed for detecting the radiation in the Middle Infrared spectral range from 800 to 2400 nm. Heterostructures with the InGaAsSb sensitive layer and the AlGaAsSb "window" are grown on GaSb substrates.

- Photodiodes **PD24-20-TEC** are placed in standard 9 mm package TO-5. Thermocooler and thermoresistor are mounted inside package TO-5.

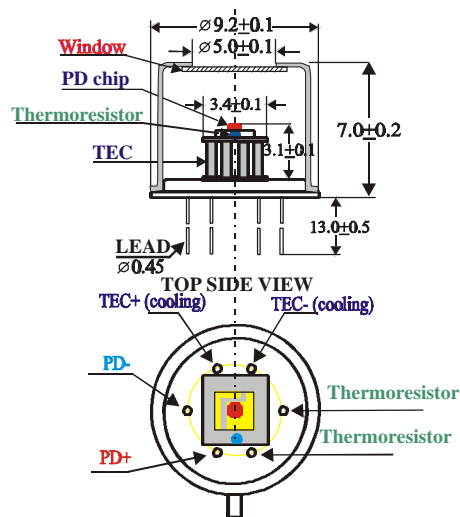
- Photodiodes **PD24-20-TEC** have the photosensitive area with diameter of 2 mm.

Fast response makes possible their use for the detection of high frequency modulated laser or LED emission.

- Related products: **PD24-20** can be used in optical pair with our **LED16÷LED23** and **LD200÷LD230**. We offer the preamplifier model **AM-04** suitable for **PD24-20**



Package TO-5



Parameters	t= -10° C	t=22° C	
Cut-off wavelength, μm (at 10%)	2.35	2.40	
Responsivity, A/W (λ=1.95÷2.1μm)	0.9 – 1.1		
Dark Current, μA (V= -0.2 V)	10-20	80-150	
	(V= -0.5 V)	20-50	100-200
	(V= -1.0 V)	80-150	200-350
Impedance, kOhm (V= -10 mV)	1.5-4.0	0.4-1.2	
Capacitance, pF (V=0)	800-2000		
Rise and Fall Time, ns (V=0, 50 Ohm)	100-250		
Detectivity, D*, cm.Hz ^{1/2} /W (λ _p ,1000,1)	(0.8÷2.0) 10 ¹¹	(5÷8) 10 ¹⁰	
	Sensitive area diameter, mm		
Package	TO-5 with thermocooler and thermistor		

Main thermocooler parameters (without load)

I _{max} (Amps)	Q _{max} (Watts)	U _{max} (Volts)	ΔT _{max} °C
0.7	0.4	1.0	67

